200 W Transient Voltage Suppressor SOD-123 Flat Lead Package

The SMF5.0A Series is designed to protect voltage sensitive components from high voltage, high energy transients. Excellent clamping capability, high surge capability, low zener impedance and fast response time. Because of its small size, it is ideal for use in cellular phones, portable devices, business machines, power supplies and many other industrial/consumer applications.

Features

- Stand-off Voltage: 5 58 Volts
- Peak Power 200 Watts @ 1 ms (SMF5.0A SMF58A)
- Low Leakage
- Response Time is Typically < 1 ns
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- ESD Rating of Level 4 (8 kV Contact Discharge) per IEC61000-4-2
- EFT (Electrical Fast Transients) Rating of 40 A per IEC61000-4-4
- Low Profile Maximum Height of 1.0 mm
- Small Footprint Footprint Area of 8.45 mm²
- Supplied in 8 mm Tape and Reel 3,000 Units per Reel
- Cathode Indicated by Polarity Band
- Lead Orientation in Tape: Cathode Lead to Sprocket Holes
- Pb-Free Packages are Available

Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic

Epoxy Meets UL 94 V-0

LEAD FINISH: 100% Matte Sn (Tin)

MOUNTING POSITION: Any

QUALIFIED MAX REFLOW TEMPERATURE: 260°C

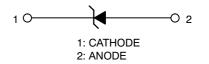
Device Meets MSL 1 Requirements



ON Semiconductor®

http://onsemi.com

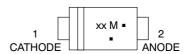
PLASTIC SURFACE MOUNT ZENER OVERVOLTAGE TRANSIENT SUPPRESSOR 5 - 58 VOLTS 200 WATT PEAK POWER





SOD-123FL CASE 498 PLASTIC

MARKING DIAGRAM



xx = Device Code (Refer to page 3)

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]		
SMFxxxAT1G	SOD-123FL (Pb-Free)	3000/Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 3 of this data sheet.

MAXIMUM RATINGS

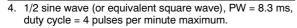
Rating	Symbol	Value	Unit
Maximum P _{pk} Dissipation (PW-10/1000 μs) (Note 1) SMF5.0A - SMF58A	P _{pk}	200	W
Maximum P _{pk} Dissipation @ T _A = 25°C, (PW-8/20 μs) (Note 2)	P _{pk}	1000	W
DC Power Dissipation @ T _A = 25°C (Note 3) Derate above 25°C Thermal Resistance, Junction–to–Ambient (Note 3)	P _D	385 4.0 325	mW mW/°C °C/W
Thermal Resistance, Junction-to-Lead (Note 3)	$R_{ heta Jcathode}$	26	°C/W
Operating and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

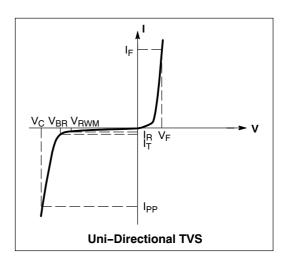
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect

- 1. Non-repetitive current pulse at $T_A = 25^{\circ}\text{C}$, per waveform of Figure 2. 2. Non-repetitive current pulse at $T_A = 25^{\circ}\text{C}$, per waveform of Figure 3. 3. Mounted with recommended minimum pad size, DC board FR-4.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted, V_F = 3.5 V Max. @ I_F (Note 4) = 12 A)

Symbol	Parameter				
I _{PP}	Maximum Reverse Peak Pulse Current				
V _C	Clamping Voltage @ I _{PP}				
V _{RWM}	Working Peak Reverse Voltage				
I _R	Maximum Reverse Leakage Current @ V _{RWM}				
V_{BR}	Breakdown Voltage @ I _T				
I _T	Test Current				
I _F	Forward Current				
V _F	Forward Voltage @ I _F				





ELECTRICAL CHARACTERISTICS ($T_L = 30$ °C unless otherwise noted, $V_F = 1.25$ Volts @ 200 mA)

		V _{RWM} (V)	V _{BR} @ I _T (V) (Note 6)		Ι _Τ	I _R @ V _{RWM}	V _{C(Max)}	I _{PP(Max)} (A)	
Device*	Marking	(Note 5)	Min	Nom	Max	(mA)	(μΑ)	(V)	(Note 7)
SMF5.0A, G	KE	5	6.4	6.7	7	10	400	9.2	21.7
SMF6.0A, G	KG	6	6.67	7.02	7.37	10	400	10.3	19.4
SMF6.5A, G	KK	6.5	7.22	7.6	7.98	10	250	11.2	17.9
SMF7.0A, G	KM	7	7.78	8.2	8.6	10	100	12	16.7
SMF7.5A, G	KP	7.5	8.33	8.77	9.21	1	50	12.9	15.5
SMF8.0A, G	KR	8	8.89	9.36	9.83	1	25	13.6	14.7
SMF8.5A, G	KT	8.5	9.44	9.92	10.4	1	10	14.4	13.9
SMF9.0A, G	KV	9	10	10.55	11.1	1	5	15.4	13.0
SMF10A, G	KX	10	11.1	11.7	12.3	1	2.5	17	11.8
SMF11A, G	KZ	11	12.2	12.85	13.5	1	2.5	18.2	11.0
SMF12A, G	LE	12	13.3	14	14.7	1	2.5	19.9	10.1
SMF13A, G	LG	13	14.4	15.15	15.9	1	1	21.5	9.3
SMF14A, G	LK	14	15.6	16.4	17.2	1	1	23.2	8.6
SMF15A, G	LM	15	16.7	17.6	18.5	1	1	24.4	8.2
SMF16A, G	LP	16	17.8	18.75	19.7	1	1	26	7.7
SMF17A, G	LR	17	18.9	19.9	20.9	1	1	27.6	7.2
SMF18A, G	LT	18	20	21	22.1	1	1	29.2	6.8
SMF20A, G	LV	20	22.2	23.35	24.5	1	1	32.4	6.2
SMF22A, G	LX	22	24.4	25.6	26.9	1	1	35.5	5.6
SMF24A, G	LZ	24	26.7	28.1	29.5	1	1	38.9	5.1
SMF26A, G	ME	26	28.9	30.4	31.9	1	1	42.1	4.8
SMF28A, G	MG	28	31.1	32.8	34.4	1	1	45.4	4.4
SMF30A, G	MK	30	33.3	35.1	36.8	1	1	48.4	4.1
SMF33A, G	MM	33	36.7	38.7	40.6	1	1	53.3	3.8
SMF36A, G	MP	36	40	42.1	44.2	1	1	58.1	3.4
SMF40A, G	MR	40	44.4	46.8	49.1	1	1	64.5	3.1
SMF43A, G	MT	43	47.8	50.3	52.8	1	1	69.4	2.9
SMF45A, G	MV	45	50	52.65	55.3	1	1	72.7	2.8
SMF48A, G	MX	48	53.3	56.1	58.9	1	1	77.4	2.6
SMF51A, G	MZ	51	56.7	59.7	62.7	1	1	82.4	2.4
SMF54A, G	NE	54	60	63.15	66.3	1	1	87.1	2.3
SMF58A, G	NG	58	64.4	67.8	71.2	1	1	93.6	2.1

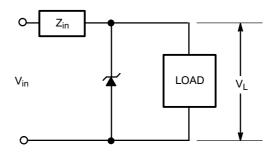
^{5.} A transient suppressor is normally selected according to the Working Peak Reverse Voltage (V_{RWM}) which should be equal to or greater than the DC or continuous peak operating voltage level.

6. V_{BR} measured at pulse test current I_T at ambient temperature of 25°C.

7. Surge current waveform per Figure 2 and derate per Figure 3.

^{*}The "G" suffix indicates Pb-Free package available.

TYPICAL PROTECTION CIRCUIT



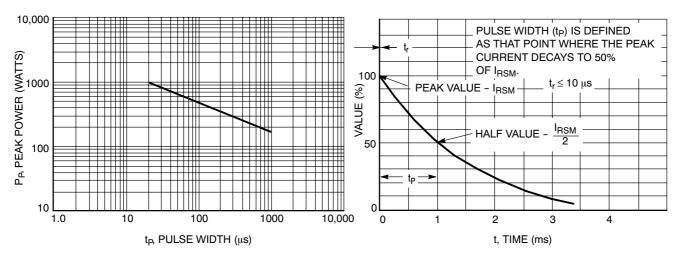


Figure 1. Pulse Rating Curve

Figure 2. 10 X 1000 µs Pulse Waveform

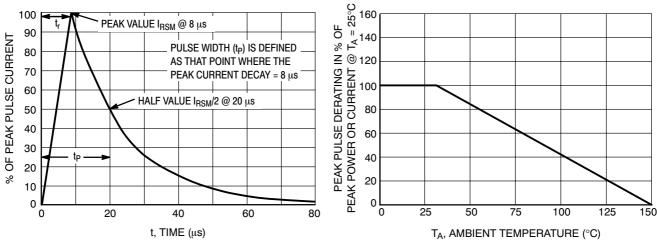


Figure 3. 8 X 20 µs Pulse Waveform

Figure 4. Pulse Derating Curve

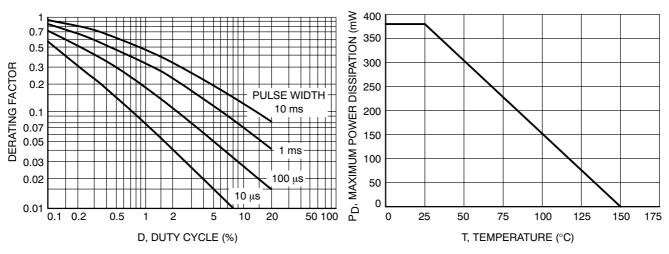


Figure 5. Typical Derating Factor for Duty Cycle

Figure 6. Steady State Power Derating

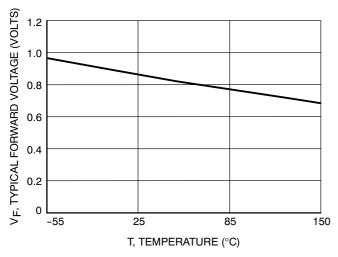


Figure 7. Forward Voltage

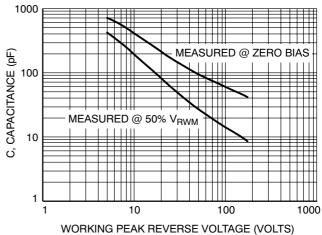
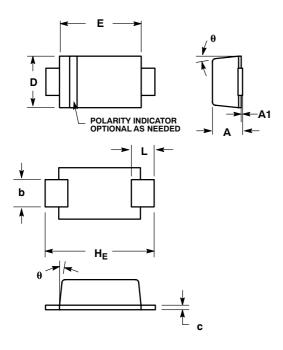


Figure 8. Capacitance versus Working Peak Reverse Voltage

PACKAGE DIMENSIONS

SOD-123FL CASE 498-01 **ISSUE A**

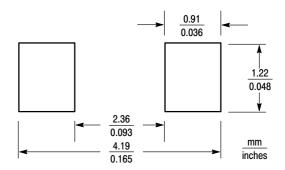


- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- DIMENSIONING AND TOLEHANCING PEH ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH.
 DIMENSIONS D AND J ARE TO BE MEASURED ON FLAT SECTION
 OF THE LEAD: BETWEEN 0.10 AND 0.25 MM FROM THE LEAD TIP.

	М	ILLIMETE	RS	INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.90	0.95	1.00	0.035	0.037	0.039	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
b	0.70	0.90	1.10	0.028	0.035	0.043	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	1.50	1.65	1.80	0.059	0.065	0.071	
E	2.50	2.70	2.90	0.098	0.106	0.114	
L	0.55	0.75	0.95	0.022	0.030	0.037	
HE	3.40	3.60	3.80	0.134	0.142	0.150	
θ	0°	-	8°	0°	-	8°	

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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